NSN 5961-01-023-2827

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-023-2827

Inclosure Material:

Metal

Overall Length:

1.269 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Mounting hardware

Overall Width Across Flats:

0.875 inches

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 collector to emitter voltage, dc and 25.0 emitter to base voltage, instantaneous and 235.0 collector to base voltage, dc

Current Rating Per Characteristic:

20.00 amperes source cutoff current and 7.50 amperes source cutoff current

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0